

Binding energy (eV)

2230

2225

2220

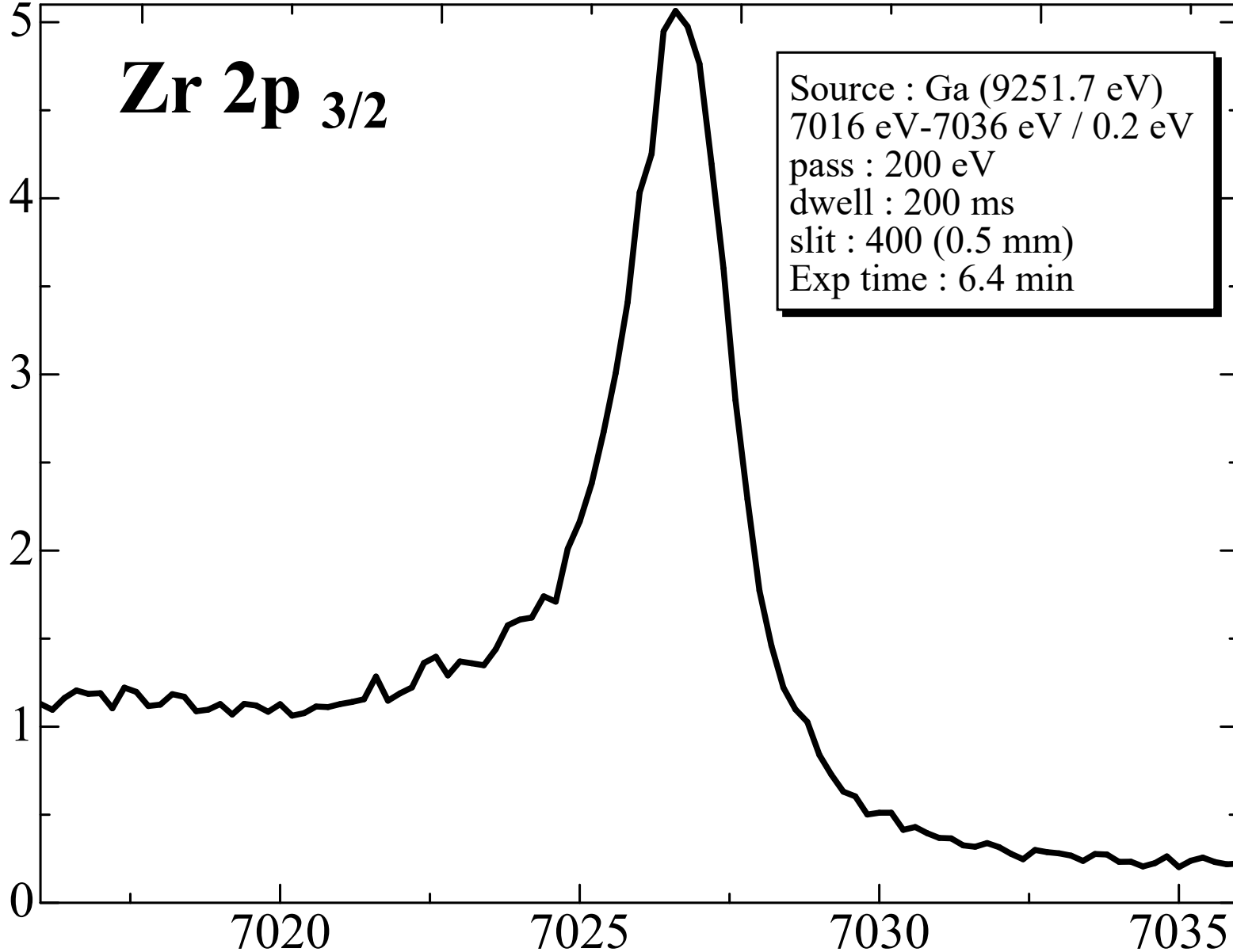
2215

$[\times 10^4]$

Photoelectron intensity (count)

Zr 2p $3/2$

Source : Ga (9251.7 eV)
7016 eV-7036 eV / 0.2 eV
pass : 200 eV
dwell : 200 ms
slit : 400 (0.5 mm)
Exp time : 6.4 min



Kinetic energy (eV)